

SANYO Semiconductors DATA SHEET

LA6393D LA6393S

Monolithic Linear IC High-Performance Dual Comparator

Overview

The LA6393D and 6393S are high-performance dual comparators that are capable of operating from a single power supply voltage over a wide range of 2 to 36V. Because of their excellent input characteristics and low power, they can be very conveniently applied to multisignal parallel comparator circuits that require high-density assembly.

Features

- LA6393D: DIP-8 pin package, LA6393S: SIP-9 pin package.
- Wide operating power-supply voltage range (Single power supply: 2.0 to 36.0V, dual power supplies: ± 1.0 to ± 18.0 V).
- Wide common-mode input voltage range (0 to V_{CC}-1.5V).
- Open-collector output enabling wired OR.
- Small current drain (0.6mA) and low power.

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		36	V
Differential input voltage	V _{ID}		36	V
Common-mode input voltage range	VICM		-0.3 to +36	V
Allowable power dissipation	Pd max		570	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

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Operating Characteristics at Ta = 25°C, V_{CC} = 5V

Parameter	Symbol	Conditions	Test Circuit	Ratings			
				min	typ	max	unit
Input offset voltage	VIO		1		±1	±5	mV
Input offset current	l _{IO}		2		±5	±50	nA
Input bias current	۱ _B		3		25	250	nA
Common-mode input voltage range	VICM			0		V _{CC} -1.5	V
Supply current	ICC	R _L = ∞	4		0.6	1	mA
Voltage gain	VG	$R_L = 15k\Omega$	5		200		V/mV
Response time		V_{RL} = 5V, R_L = 5.1k Ω	6		1.3		μS
Output sink current	ISINK	$V_{IN^{-}} = 1V, V_{IN} + = 0V, V_{O} \le 1.5V$	7	6	16		mA
Output saturation current	V _{OL}	V _{IN} - = 1V, V _{IN} + = 0V, I _{SINK} ≤3mA	8		0.2	0.4	V
Output leakage current	ILEAK	$V_{IN^{-}} = 0V, V_{IN} + = 1V, V_{O} = 5V$	9		0.1		nA

Package Dimensions

unit: mm (typ) 3001D [LA6393D]



Package Dimensions

unit: mm (typ) 3017D [LA6393S]







Equivalent Circuit



Pin Assignment







ILA07112





2 3 5 7 1.0

Output Sink Current, ISINK - mA

2 3

5 7 0.1

I_B - Ta

ILA07115

2

5 7 10

LA6393D / LA6393S



Sample Application Circuits



Square wave generator

Voltage comparator (with hysteresis)



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